

DATA SHEET

74LVC1G07 Buffer with open-drain output

Product specification
Supersedes data of 2003 Mar 07

2004 Sep 07

Buffer with open-drain output**74LVC1G07****FEATURES**

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B/JESD36 (2.7 V to 3.6 V).
- 24 mA output drive ($V_{CC} = 3.0$ V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- ESD protection:
 - HBM EIA/JESD22-A114-B exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 °C to $+85$ °C and -40 °C to $+125$ °C.

DESCRIPTION

The 74LVC1G07 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The input can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device as translator in a mixed 3.3 V and 5 V environment.

Schmitt trigger action at the input makes the circuit tolerant for slower input rise and fall time.

The 74LVC1G07 provides the non-inverting buffer.

The output of the device is an open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

QUICK REFERENCE DATA

$GND = 0$ V; $T_{amb} = 25$ °C; $t_r = t_f \leq 2.5$ ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PLZ}/t_{PZL}	propagation delay inputs A to output Y	$V_{CC} = 1.8$ V; $C_L = 30$ pF; $R_L = 1$ kΩ	2.6	ns
		$V_{CC} = 2.5$ V; $C_L = 30$ pF; $R_L = 500$ Ω	1.7	ns
		$V_{CC} = 2.7$ V; $C_L = 50$ pF; $R_L = 500$ Ω	2.3	ns
		$V_{CC} = 3.3$ V; $C_L = 50$ pF; $R_L = 500$ Ω	2.2	ns
		$V_{CC} = 5.0$ V; $C_L = 50$ pF; $R_L = 500$ Ω	1.6	ns
C_I	input capacitance		5	pF
C_{PD}	power dissipation capacitance per gate	$V_{CC} = 3.3$ V; notes 1 and 2	7	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

$$\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of the outputs.}$$

2. The condition is $V_I = GND$ to V_{CC} .

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FUNCTION TABLE

See note 1.

INPUT	OUTPUT
A	Y
L	L
H	Z

Note

1. H = HIGH voltage level;
- L = LOW voltage level;
- Z = high-impedance OFF-state.

ORDERING INFORMATION

TYPE NUMBER	TEMPERATURE RANGE	PACKAGE				
		PINS	PACKAGE	MATERIAL	CODE	MARKING
74LVC1G07GW	-40 °C to +125 °C	5	SC-88A	plastic	SOT353	VS
74LVC1G07GV	-40 °C to +125 °C	5	SC-74A	plastic	SOT753	V07
74LVC1G07GM	-40 °C to +125 °C	6	XSON6	plastic	SOT886	VS

PINNING

PIN (TSSOP5 AND VSSOP5)	PIN (XSON6)	SYMBOL	DESCRIPTION
1	1	n.c.	not connected
2	2	A	data input A
3	3	GND	ground (0 V)
4	4	Y	data output Y
-	5	n.c.	not connected
5	6	V _{CC}	supply voltage

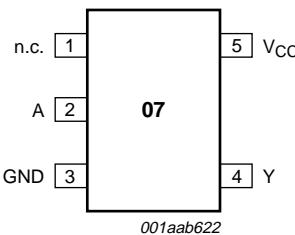
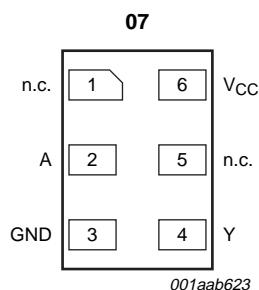


Fig.1 Pin configuration TSSOP5 and VSSOP5.



Transparent top view

Fig.2 Pin configuration XSON6.

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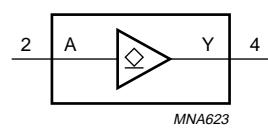


Fig.3 Logic symbol.

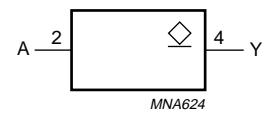


Fig.4 IEC logic symbol.

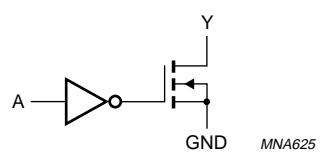


Fig.5 Logic diagram.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		1.65	5.5	V
V_I	input voltage		0	5.5	V
V_O	output voltage	active mode	0	5.5	V
		$V_{CC} = 0$ V; Power-down mode	0	5.5	V
T_{amb}	operating ambient temperature		-40	+125	°C
t_r, t_f	input rise and fall times	$V_{CC} = 1.65$ V to 2.7 V	0	20	ns/V
		$V_{CC} = 2.7$ V to 5.5 V	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		-0.5	+6.5	V
I_{IK}	input diode current	$V_I < 0$ V	-	-50	mA
V_I	input voltage	note 1	-0.5	+6.5	V
I_{OK}	output diode current	$V_O > V_{CC}$ or $V_O < 0$ V	-	±50	mA
V_O	output voltage	active mode; notes 1 and 2	-0.5	+6.5	V
		Power-down mode; notes 1 and 2	-0.5	+6.5	V
I_O	output sink current	$V_O = 0$ V to V_{CC}	-	±50	mA
I_{CC}, I_{GND}	V_{CC} or GND current		-	±100	mA
T_{stg}	storage temperature		-65	+150	°C
P_D	power dissipation	$T_{amb} = -40$ °C to +125 °C	-	250	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. When $V_{CC} = 0$ V (Power-down mode), the output voltage can be 5.5 V in normal operation.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. ⁽¹⁾	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = -40 °C to +85 °C							
V _{IH}	HIGH-level input voltage		1.65 to 1.95	0.65 × V _{CC}	—	—	V
			2.3 to 2.7	1.7	—	—	V
			2.7 to 3.6	2.0	—	—	V
			4.5 to 5.5	0.7 × V _{CC}	—	—	V
V _{IL}	LOW-level input voltage		1.65 to 1.95	—	—	0.35 × V _{CC}	V
			2.3 to 2.7	—	—	0.7	V
			2.7 to 3.6	—	—	0.8	V
			4.5 to 5.5	—	—	0.3 × V _{CC}	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} I _O = 100 µA I _O = 4 mA I _O = 8 mA I _O = 12 mA I _O = 24 mA I _O = 32 mA	1.65 to 5.5	—	—	0.1	V
			1.65	—	—	0.45	V
			2.3	—	—	0.3	V
			2.7	—	—	0.4	V
			3.0	—	—	0.55	V
			4.5	—	—	0.55	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	1.65 to 5.5	—	±0.1	±5	µA
I _{OZ}	output leakage current	V _I = V _{IH} ; V _O = 5.5 V or GND	1.65 to 5.5	—	0.1	±10	µA
I _{off}	power OFF leakage current	V _I or V _O = 5.5 V	0	—	±0.1	±10	µA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	5.5	—	0.1	10	µA
ΔI _{CC}	additional quiescent supply current per pin	V _I = V _{CC} – 0.6 V; I _O = 0 A	2.3 to 5.5	—	5	500	µA

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.⁽¹⁾	MAX.	UNIT
		OTHER	V_{CC} (V)				
T_{amb} = -40 °C to +125 °C							
V _{IH}	HIGH-level input voltage		1.65 to 1.95	0.65 × V _{CC}	—	—	V
			2.3 to 2.7	1.7	—	—	V
			2.7 to 3.6	2.0	—	—	V
			4.5 to 5.5	0.7 × V _{CC}	—	—	V
V _{IL}	LOW-level input voltage		1.65 to 1.95	—	—	0.35 × V _{CC}	V
			2.3 to 2.7	—	—	0.7	V
			2.7 to 3.6	—	—	0.8	V
			4.5 to 5.5	—	—	0.3 × V _{CC}	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} I _O = 100 µA I _O = 4 mA I _O = 8 mA I _O = 12 mA I _O = 24 mA I _O = 32 mA	1.65 to 5.5	—	—	0.1	V
			1.65	—	—	0.70	V
			2.3	—	—	0.45	V
			2.7	—	—	0.60	V
			3.0	—	—	0.80	V
			4.5	—	—	0.80	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	1.65 to 5.5	—	—	±100	µA
I _{OZ}	output leakage current	V _I = V _{IH} ; V _O = 5.5 V or GND	1.65 to 5.5	—	—	±100	µA
I _{off}	power OFF leakage current	V _I or V _O = 5.5 V	0	—	—	±200	µA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	5.5	—	—	200	µA
ΔI _{CC}	additional quiescent supply current per pin	V _I = V _{CC} - 0.6 V; I _O = 0 A	2.3 to 5.5	—	—	5000	µA

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

Buffer with open-drain output

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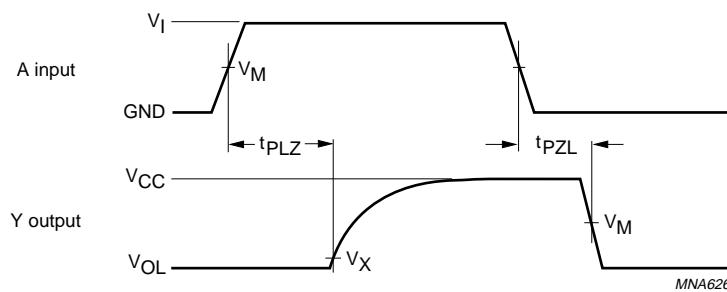
AC CHARACTERISTICSGND = 0 V; $t_r = t_f \leq 2.0$ ns.

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V_{cc} (V)				
$T_{amb} = -40$ °C to +85 °C							
t_{PLZ}/t_{PZL}	propagation delay A to Y	see Figs 6 and 7	1.65 to 1.95	1.0	2.6	6.7	ns
			2.3 to 2.7	0.5	1.7	5.5	ns
			2.7	0.5	2.3	4.7	ns
			3.0 to 3.6	0.5	2.2	4.2	ns
			4.5 to 5.5	0.5	1.6	3.5	ns
$T_{amb} = -40$ °C to +125 °C							
t_{PLZ}/t_{PZL}	propagation delay A to Y	see Figs 6 and 7	1.65 to 1.95	1.0	—	2	ns
			2.3 to 2.7	0.5	—	7	ns
			2.7	0.5	—	6	ns
			3.0 to 3.6	0.5	—	5.5	ns
			4.5 to 5.5	0.5	—	4.5	ns

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AC WAVEFORMS

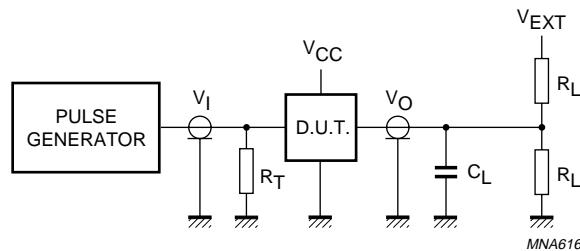


V_{CC}	V_M	V_X	V_I
1.65 V to 1.95 V	$0.5 \times V_{CC}$	$V_{OL} + 0.15$ V	V_{CC}
2.3 V to 2.7 V	$0.5 \times V_{CC}$	$V_{OL} + 0.15$ V	V_{CC}
2.7 V	1.5 V	$V_{OL} + 0.3$ V	2.7 V
3.0 V to 3.6 V	1.5 V	$V_{OL} + 0.3$ V	2.7 V
4.5 V to 5.5 V	$0.5 \times V_{CC}$	$V_{OL} + 0.3$ V	V_{CC}

Fig.6 Input A to output Y propagation delay times.

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V_{CC}	V_I	C_L	R_L	V_{EXT}		
				t_{PLH}/t_{PHL}	t_{PZH}/t_{PHZ}	t_{PZL}/t_{PLZ}
1.65 V to 1.95 V	V_{CC}	30 pF	1 k Ω	open	GND	$2 \times V_{CC}$
2.3 V to 2.7 V	V_{CC}	30 pF	500 Ω	open	GND	$2 \times V_{CC}$
2.7 V	2.7 V	50 pF	500 Ω	open	GND	6 V
3.0 V to 3.6 V	2.7 V	50 pF	500 Ω	open	GND	6 V
4.5 V to 5.5 V	V_{CC}	50 pF	500 Ω	open	GND	$2 \times V_{CC}$

Definitions for test circuit:

R_L = Load resistor.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig.7 Load circuitry for switching times.

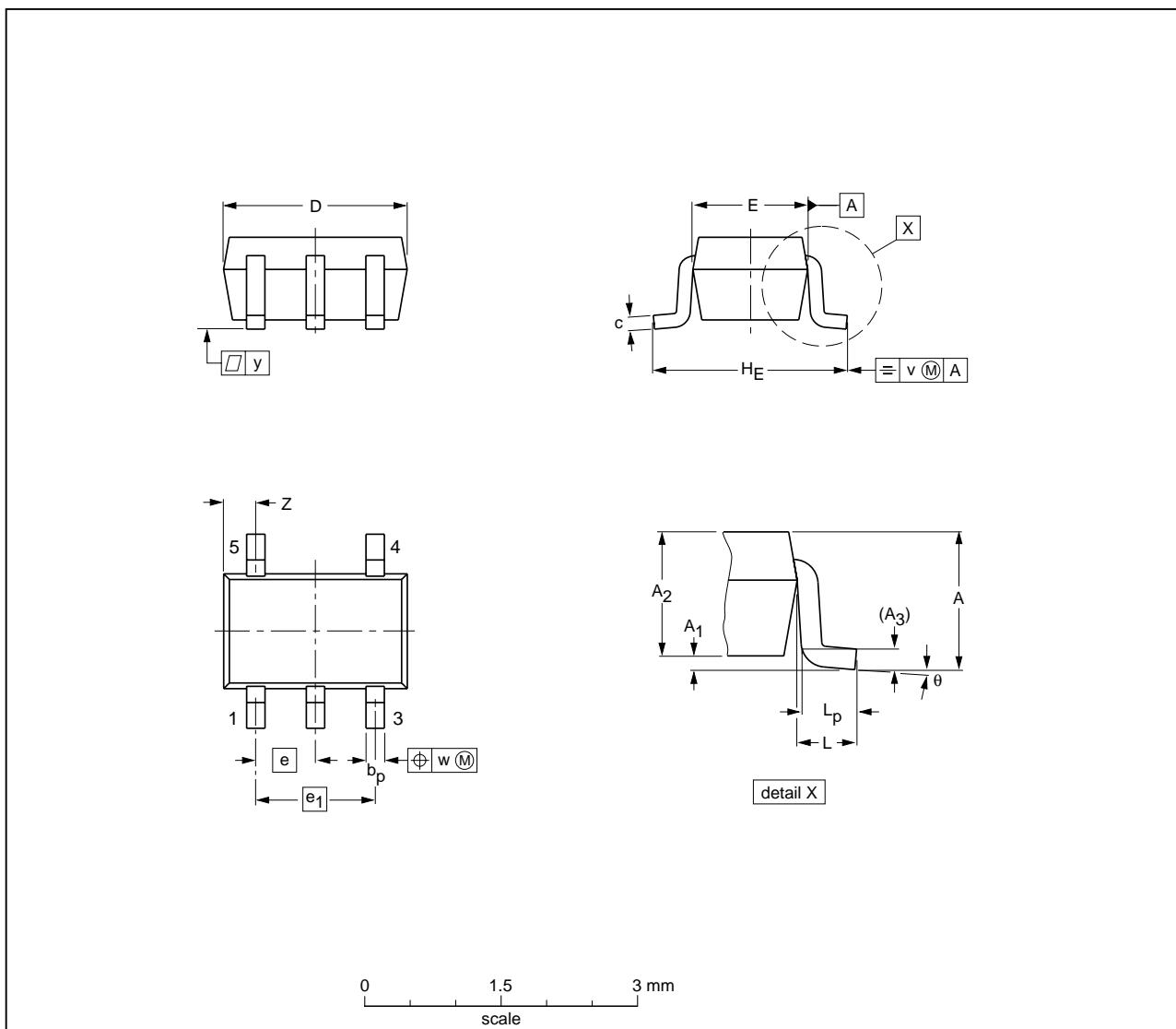
Buffer with open-drain output

74LVC1G07

PACKAGE OUTLINES

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	H _E	L	L _p	v	w	y	Z ⁽¹⁾	θ
mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

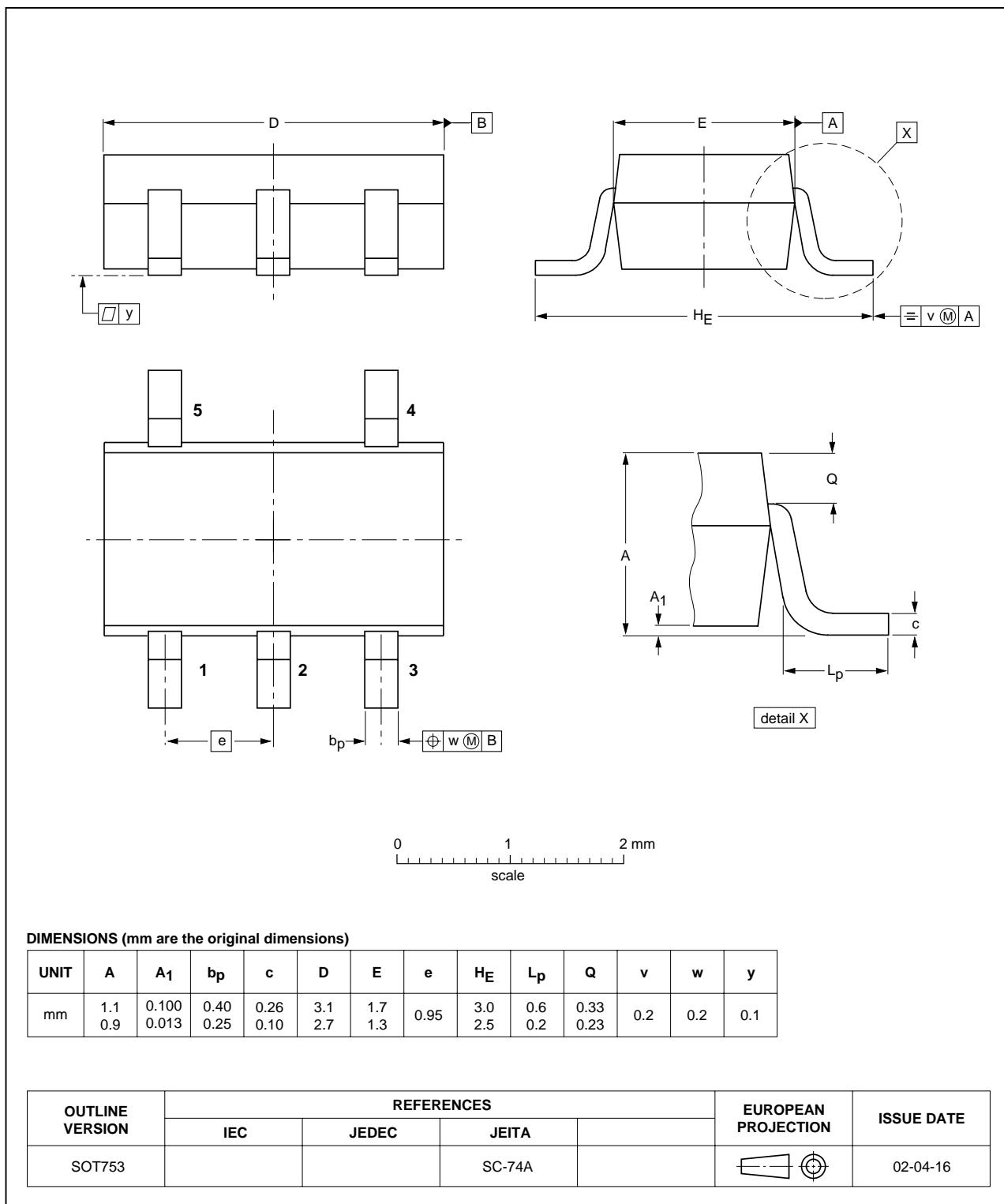
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT353-1		MO-203	SC-88A			-00-09-01-03-02-19

Buffer with open-drain output

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Plastic surface mounted package; 5 leads

SOT753

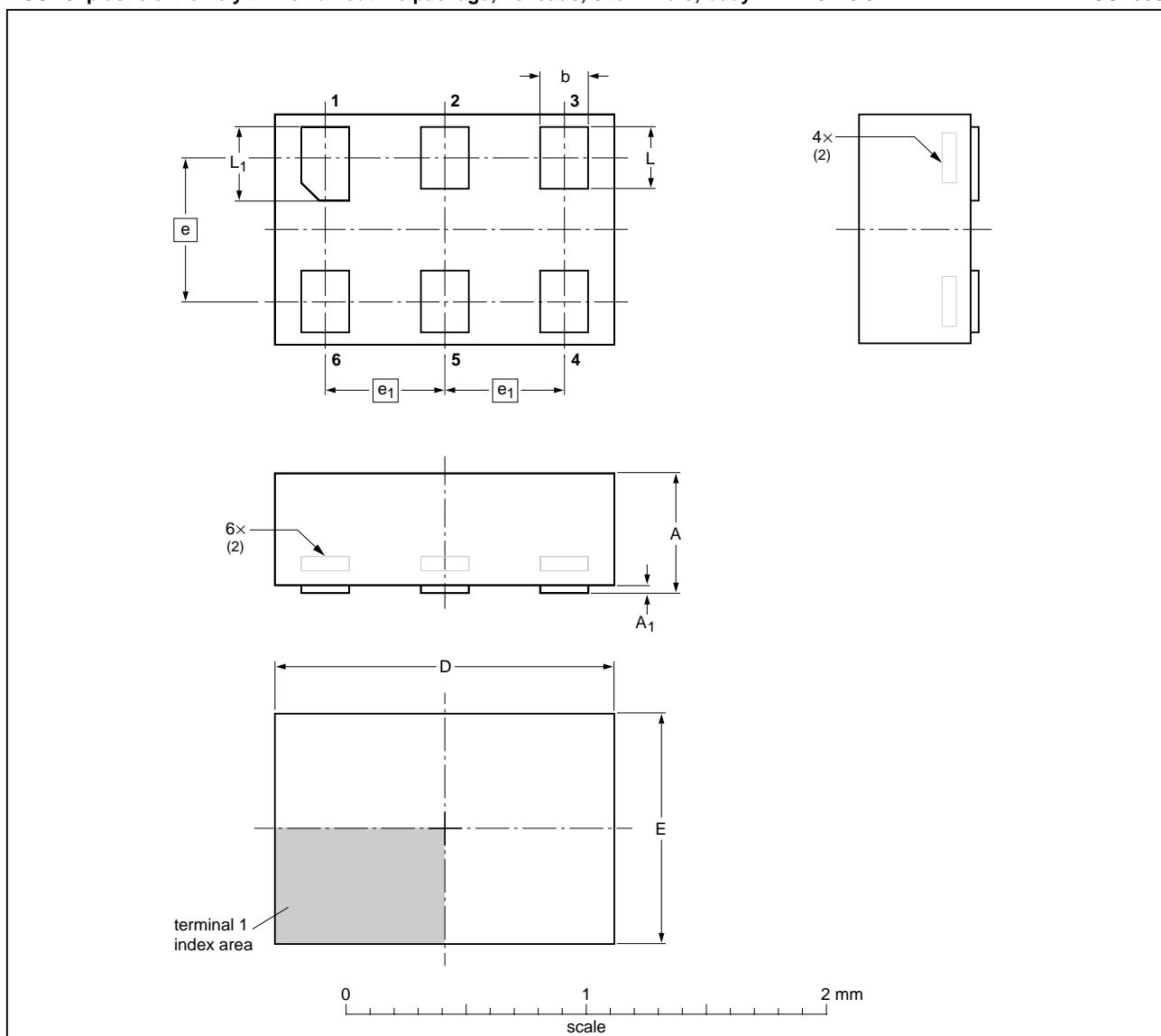


Buffer with open-drain output

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XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886



DIMENSIONS (mm are the original dimensions)

UNIT	$A^{(1)}$ max	A_1 max	b	D	E	e	e_1	L	L_1
mm	0.5	0.04	0.25 0.17	1.5 1.4	1.05 0.95	0.6	0.5	0.35 0.27	0.40 0.32

Notes

1. Including plating thickness.
2. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT886		MO-252				04-07-15 04-07-22

Buffer with open-drain output

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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